

## 30A 300V Fast recovery diode

### 1 Description

30A, 300V Ultrafast Diodes They have a low forward voltage drop and are of planar, silicon nitride passivated, ion-implanted, epitaxial construction. These devices are intended for use as energy steering/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and ultrafast recovery with soft recovery characteristics minimizes ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistor

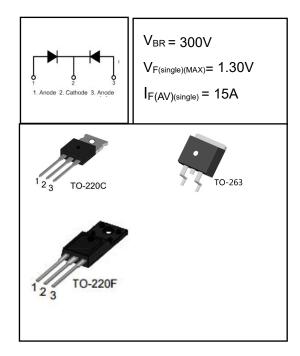
TO-220F provides insulation voltage rated at 2000V RMS from all three terminals to external heatsink.

#### 2 Features

- Low power loss,
- high efficiency Low forward voltage,
- high current capability High surge capacity
- Super fast recovery times
- high voltage

### 3 Applications

- Switching Power Supply
- Power Switching Circuits
- General Purpose



#### 4 Electrical Characteristics

### **4.1 Absolute Maximum Ratings** (Tc=25 °C, unless otherwise noted)

PARAMETER		SYMBOL	VALUE	UNIT
Peak Repetitive Reverse Voltage		V <sub>RRM</sub>	300	V
Working Peak Reverse Voltage		V <sub>RWM</sub>	300	V
DC Blocking Voltage	V <sub>R</sub>	300	V	
Average Rectified Forward Current(single)	TO-220/263/,T <sub>C</sub> =135°C		15	Α
Average Rectified Forward Current(double)	TO-220F,T <sub>C</sub> =100℃	I <sub>F(AV)</sub>	30	Α
Repetitive Peak Surge Current(single)		I <sub>FRM</sub>	20	Α
Nonrepetitive Peak Surge Current(single) t <sub>p</sub> =8.3ms		I <sub>FSM</sub>	150	Α
Avalanche Energy(single) L=1mH		E <sub>AS</sub>	20	mJ
Operating Junction Temperature Range		Tj	<b>-</b> 55∼150	$^{\circ}$ C
Storage Temperature Range		T <sub>stg</sub>	-55~150	$^{\circ}$

#### 4.2 Thermal Characteristics

PARAMETER	SYMBOL		VALUE		UNIT
PARAWETER	STIVIBUL	TO-220F	TO-220	TO-3P	UNIT
Thermal Resistance, Junction to Case-sink	R <sub>th</sub> JC	2.1	1.1	0.75	°C/W



### 4.3 Electrical Characteristics

(Tc=25<sup>°</sup>C,unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Maximum Instantaneous	V <sub>F</sub>	I <sub>F</sub> =15A	-	1.10	1.30	V
Forward Voltage		I <sub>F</sub> =15A, T <sub>C</sub> = 150°C	-	-	1.20	V
		I <sub>F</sub> = 20A	-	1.20	1.40	V
Maximum Instantaneous	I <sub>R</sub>	V <sub>R</sub> = 300V	-	-	5	uA
Reverse		V <sub>R</sub> = 300V, TC = 150°C	-	-	1	mA
Maximum Reverse	t <sub>rr</sub>	V <sub>R</sub> =30V IF=1A -dI/dt=50A/us	-	26	35	ns
Recovery Time						
Total capacitance	C <sub>tot</sub>	V <sub>R</sub> =0V f=1MHz	-	210	-	pF
DC Blocking Voltage	$V_{BR}$	I <sub>R</sub> =100uA	310	340	-	V

### **DEFINITIONS**

VF = Instantaneous forward voltage (pw = 300µs, D = 2%).

IR = Instantaneous reverse current.

 $R\theta JC$  = Thermal resistance junction to case.

pw = pulse width.

D = duty cycle.

# 5 Typical characteristics diagrams

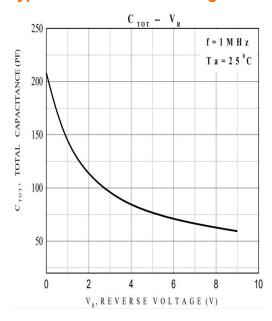


FIGURE 1. Total capacitance vs Voltage

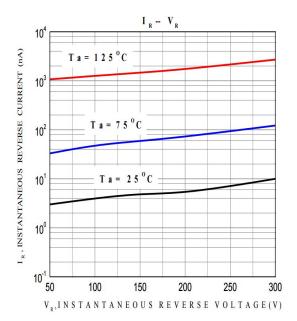


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE



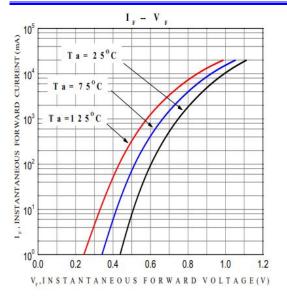


FIGURE 3. FORWARD CURRENT vs FORWARD VOLTAGE

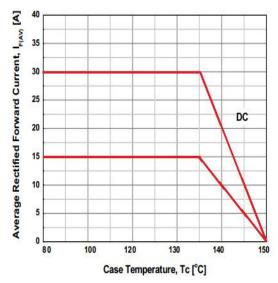


FIGURE 4. CURRENT DERATING CURVE

# 6 Typical Test Circuit and Waveform

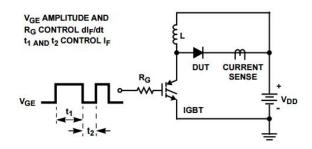


FIGURE 5. trr TEST CIRCUIT

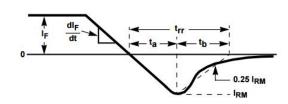


FIGURE 6. trr WAVEFORMS AND DEFINITIONS

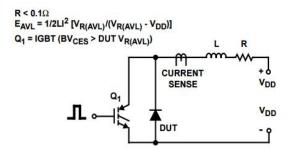


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT FIGURE

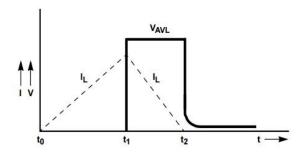


FIGURE8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

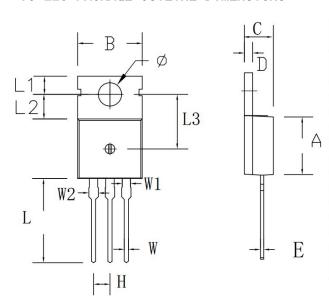


# 7 Product Specifications and Packaging Models

Product Model	Package Type	Mark Name	RoHS	Package	Quantity
MUR3030CT	TO-220	MUR3030CT	Pb-free	Tube	1000/box
MURF3030CT	TO-220F	MURF3030CT	Pb-free	Tube	1000/box
MURE3030CT	TO-263	MURE3030CT	Pb-free	Tube	1000/box

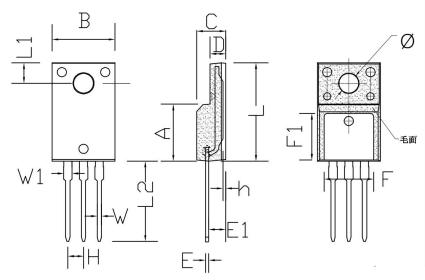
## 8 Dimensions

# TO-220 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In	n Millimeters	Dimensions	In Inches
Symbol	min.	max.	min.	max.
A	8. 80	9. 30	0.346	0.366
В	9. 70	10.30	0. 382	0.406
С	4. 25	4. 75	0. 167	0. 187
D	1. 20	1. 45	0.047	0.057
Е	0.40	0.60	0.016	0.024
Н	2. 54	TYP	0. 100	TYP
W	0.60	0.95	0.024	0. 037
W1	1.05	1. 45	0.041	0.057
W2	1. 20	1.60	0.047	0.063
L	12.60	13. 40	0. 496	0. 528
L1	2. 45	2.95	0.096	0. 116
L2	3. 45	3. 95	0. 136	0.156
L3	8. 15	8. 65	0. 321	0. 341
Φ	3. 50	3. 90	0.138	0. 154

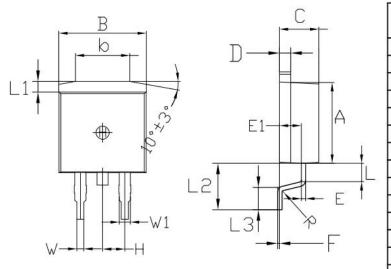
## TO-220F PACKAGE OUTLINE DIMENSIONS



C	DimensionsIn	Millimeters	DimensionsIn Inches		
Symbol	min.	max.	min.	max.	
Α	8.80	9.30	0.346	0.366	
В	10.00	10.50	0.394	0.413	
С	4.30	4.90	0.169	0.193	
D	2.30	2.70	0.091	0.106	
L	15.55	16.15	0.612	0.636	
h	0.40	0.60	0.016	0.024	
L1	3.15	3.55	0.124	0.140	
L2	12.65	13.35	0.498	0.526	
W	0.70	0.90	0.028	0.035	
W1	1.15	1.55	0.045	0.061	
Н	2.54 TYP		0.100	TYP	
Е	0.48	0.53	0.019	0.021	
ф	2.90	3.40	0.114	0.134	
E1	2.40	2.90	0.094	0.114	
F	7.75	8.25	0.305	0.325	
F1	7.35	7.85	0.289	0.309	



## TO-263 PACKAGE OUTLINE DIMENSIONS



Comb a 1	Dimensions In	Millimeters	Dimensions	In Inches
Symbol	min.	max.	min.	max.
A	8.80	9.30	0.346	0.366
В	9. 70	10. 30	0. 382	0. 406
C	4. 25	4. 75	0. 167	0. 187
D	1.20	1.45	0.047	0.057
Е	0. 40	0.60	0.016	0.024
L	12. 25	13. 75	0. 482	0. 541
L1	1.15	1.45	0.045	0.057
R	0.24	0. 26	0.0095	0.0102
W	0.80	0.82	0. 0315	0. 0323
W1	1. 20	1. 30	0. 047	0.051
Н	2. 54	TYP	0. 200	TYP
b	5. 50	6. 50	0. 216	0. 256
E1	2. 4	2.6	0.0946	0. 1024
L2	5. 20	5. 80	0. 205	0. 228
L3	2. 20	3. 20	0.087	0. 126
F	0. 03	0. 23	0.0012	0.0091

#### 9 Attentions

- Jiangsu Donghai Semiconductor Co.,Ltd.. reserves the right to change the specification without prior notice! The
  customer should obtain the latest version of the information before making the order and verify that the information is
  complete and up to date.
- It is the responsibility of the purchaser for any failure or failure of any semiconductor product under certain conditions. It is the responsibility of the purchaser to comply with safety standards and to take safety measures in the system design and machine manufacturing of Jiangsu Donghai Semiconductor Co.,Ltd. products in order to avoid potential risk of failure. Injury or property damage.
- Product promotion is endless, our company will be dedicated to provide customers with better products.

### 10 Appendix

### Revision history:

Date	REV.	Description	Page
2017.07.22	1.0	Original	